RELIABILITY REPORT

FOR

MAX6386XSxxDx

PLASTIC ENCAPSULATED DEVICES

October 5, 2003

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Written by

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Conclusion

The MAX6386 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

The MAX6386 microprocessor (μP) supervisory circuit monitors power supply voltages from +1.8V to +5.0V while consuming only $3\mu A$ of supply current at +1.8V. Whenever V_{CC} falls below the factory-set reset thresholds, the reset output asserts and remains asserted for a minimum reset timeout period after V_{CC} rises above the reset threshold. Reset thresholds are available from +1.58V to +4.63V, in approximately 100mV increments. Seven minimum reset timeout delays ranging from 1ms to 1200ms are available.

The MAX6386 has an open-drain active-low reset output.. The MAX6386 also features a debounced manual reset input (with internal pullup resistor).

The MAX6386 is available in a 4-pin SC70 packages.

B. Absolute Maximum Ratings

<u>Item</u>	Rating		
VCC to GND	-0.3V to +6.0V		
RESET Open-Drain Output	-0.3V to +6.0V		
MR, RESET IN	-0.3V to (VCC + 0.3V)		
Input Current (VCC)	20mA		
Output Current (All Pins)	20mA		
Operating Temperature Range	-40°C to +125°C		
Storage Temperature Range	-65°C to +150°C		
Lead Temperature (soldering, 10s)	+300°C		
Continuous Power Dissipation (TA = +70°C)			
4-Pin SC70	245mW		
Derates above +70°C			
4-Pin SC70	3.1mW/°C		

II. Manufacturing Information

A. Description/Function: SC70, Single/Dual Low-Voltage, Low-Power µP Reset Circuits

B. Process: B8 (Standard .8 micron silicon gate CMOS)

C. Number of Device Transistors: 647

D. Fabrication Location: California, USA

E. Assembly Location: Malaysia

F. Date of Initial Production: October, 2000

III. Packaging Information

A. Package Type: 4-Lead SC70

B. Lead Frame: Copper

C. Lead Finish: Alloy 42

D. Die Attach: Silver-Filled Epoxy

E. Bondwire: Gold (1.0 mil dia.)

F. Mold Material: Epoxy with silica filler

G. Assembly Diagram: Buildsheet # 05-1601-0128

H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity

per JEDEC standard JESD22-A112: Level 1

IV. Die Information

A. Dimensions: 30 x 31 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

C. Interconnect: Aluminum/Copper/Silicon

D. Backside Metallization: None

E. Minimum Metal Width: .8 microns (as drawn)

F. Minimum Metal Spacing: .8 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.

H. Isolation Dielectric: SiO₂

I. Die Separation Method: Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts:

Jim Pedicord (Manager, Reliablity Operations)
Bryan Preeshl (Executive Director of QA)

Kenneth Huening (Vice President)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4389 \times 80 \times 2}$$
 (Chi square value for MTTF upper limit)

Thermal acceleration factor assuming a 0.8eV activation energy

 $\lambda = 13.57 \times 10^{-9}$ $\lambda = 13.57 \text{ F.I.T.}$ (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure the reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on lots exceeding this level. The following Burn-In Schematic (Spec. #06-5033) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (RR-1M).

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

C. E.S.D. and Latch-Up Testing

The MS58-2 die type has been found to have all pins able to withstand a transient pulse of \pm 2500V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of \pm 250mA.

Table 1 Reliability Evaluation Test Results

MAX6386XSxxDx

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	t (Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		80	0
Moisture Testir	ng (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	SC70	77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Str	ress (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0

Note 1: Life Test Data may represent plastic D.I.P. qualification lots. Note 2: Generic package/process data

Attachment #1

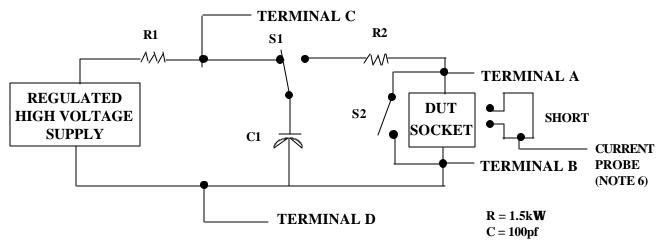
TABLE II. Pin combination to be tested. 1/2/

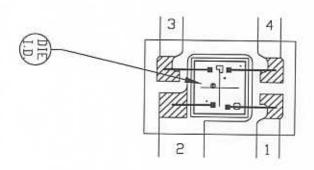
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V _{PS1} <u>3/</u>	All V _{PS1} pins
2.	All input and output pins	All other input-output pins

- 1/ Table II is restated in narrative form in 3.4 below.
- 2/ No connects are not to be tested.
- Repeat pin combination I for each named Power supply and for ground (e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_{S_1}$, $+V_{S_2}$, $+V_{REF}$, etc).

3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{SS1} , or V_{SS2} or V_{CC1} , or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
 - c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.





USE NON-CONDUCTIVE EPOXY

BONDABLE AREA

NOTE: CAVITY DOWN

PKG. CODE: X4-1	SIGNATURES	DATE	CONFIDENTIAL & PROPRIETARY		
CAV./PAD SIZE:	PKG.			BOND DIAGRAM #:	REV:
34×35	DESIGN			05-1601-0128	Α

